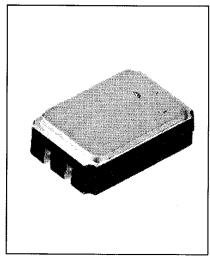
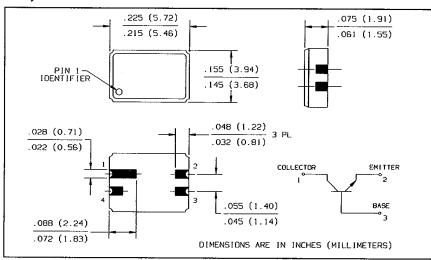


Surface Mount NPN General Purpose Transistor Types TX, TXV, 2N2222AUA





Features

- Ceramic surface mount package
- Small package to minimize circuit board area
- · Hermetically sealed
- Qualification per MIL-PRF-19500/255

Description

The TX/TXV2N2222AUA is a hermetically sealed ceramic surface mount general purpose switching transistor. The four pin ceramic package is ideal for designs where board space and device weight are important design considerations. The "UA" suffix denotes the 4 terminal leadless chip carrier package, type "A" per MIL-PRF-19500/255.

Typical screening and lot acceptance tests are provided on page 13-4. The burn-in condition is $V_{CB}=30$ V. $P_D=400$ mW, $T_A=25^{\circ}$ C, t=80 hrs. Refer to MIL-PRF-19500/255 for complete requirements. In addition , the TX and TXV versions receive 100% thermal response testing.

When ordering parts without processing, do not use a JAN prefix.

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Collector-Base Voltage 75 \
Collector-Emitter Voltage
Emitter-Base Voltage 6.0 \
Collector Current-Continuous 800 mA
Operating Junction Temperature (T _J)65° C to +200° C
Storage Junction Temperature (T _{stg})65° C to +200° C
Power Dissipation @ T _A = 25° C
Power Dissipation @ $T_C = 25^{\circ} C$
Soldering Temperature (vapor phase reflow for 30 sec.)
Soldering Temperature (heated collet for 5 sec.)
Notes:

(1) Derate linearly 6.6 mW/° C above 25° C.

Types TX, TXV, 2N2222AUA

Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS	TEST CONDITION
Off Charac	teristics				4
V _(BR) CBO	Collector-Base Breakdown Voltage	75		V	$I_C = 10 \mu A$, $I_E = 0$
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	50		٧	I _C = 10 mA, I _B = 0
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	6.0		٧	$I_E = 10 \mu\text{A}, I_C = 0$
I _{CBO}	Collector-Base Cutoff Current		10	nA	V _{CB} = 60 V, I _E = 0
			10	μΑ	V _{CB} = 60 V, I _E = 0, T _A = 150° C
I _{EBO}	Emitter-Base Cutoff Current		10	nA	V _{EB} = 4 V, I _C = 0
ICES	Collector-Emitter Cutoff Current		50	nA	V _{CE} = 50 V
On Charac	teristics				
h _{FE}	Forward-Current Transfer Ratio	50		-	V _{CE} = 10 V, I _C = 0.1 mA
		75	325	383	V _{CE} = 10 V, I _C = 1.0 mA
		100			V _{CE} = 10 V, I _C = 10 mA
		100	300	750	V _{CE} = 10 V, I _C = 150 mA ⁽²⁾
		30		(1 0)	V _{CE} = 10 V, I _C = 500 mA ⁽²⁾
		35		120	V _{CE} = 10 V, I _C = 10 mA, T _A = -55° C
VCE(SAT)	Collector-Emitter Saturation Voltage		0.3	V	I _C = 150 mA, I _B = 15 mA ⁽²⁾
			1.0	٧	I _C = 500 mA, I _B = 50 mA ⁽²⁾
V _{BE} (SAT)	Base-Emitter Saturation Voltage	0.6	1.2	V	I _C = 150 mA, I _B = 15 mA ⁽²⁾
			2.0	٧	I _C = 500 mA, I _B = 50 mA ⁽²⁾
Small-Sigr	nal Characteristics				
h _{fe}	Small Signal Forward Current Transfer Ratio	50		(14)	V _{CE} = 10 V, I _C = 1.0 mA, f = 1.0 kHz
Ih _{fe}	Small Signal Forward Current Transfer Ratio	2.5			$V_{CE} = 20 \text{ V}, I_{C} = 20 \text{ mA}, f = 100 \text{ MHz}$
Cobo	Open Circuit Output Capacitance		8.0	pF	V _{CB} = 10 V, 100 kHz ≤ f ≤ 1.0 MHz
Cibo	Input Capacitance (Output Open)		25	pF	V _{EB} = 0.5 V, 100 kHz ≤ f ≤ 1.0 MHz
Switching	Characteristics				
ton	Turn-On Time		35	ns	$V_{CC} = 30 \text{ V}, I_{C} = 150 \text{ mA}, I_{B1} = 15 \text{ mA}$
t _{off}	Turn-Off Time		300	ns	V _{CC} = 30 V, I _C = 150 mA, I _{B1} = I _{B2} = 15 mA

⁽²⁾ Pulse Width ≤ 300 μs, Duty Cycle ≤ 2.0%

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